

isc Silicon NPN Power Transistor

2SC4445

DESCRIPTION

- High Collector-Emitter Breakdown Voltage : V_{(BR)CEO}= 800V(Min)
- · High Switching Speed
- · Wide Area of Safe Operation
- 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

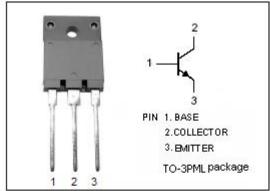


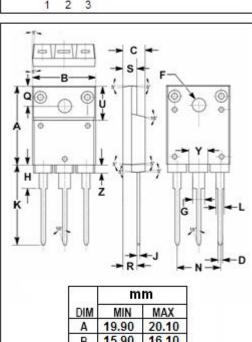
APPLICATIONS

 Designed for switching regulator and general purpose applications.

ABSOLUTE MAXIMUM RATINGS(Ta=25℃)

SYMBOL	PARAMETER	VALUE	UNIT
Vсво	Collector-Base Voltage	900	V
V _{CEO}	Collector-Emitter Voltage	800	V
V _{EBO}	Emitter-Base voltage	7	V
Ic	Collector Current-Continuous	3	Α
Ісм	Collector Current-Peak	6	Α
I _B	Base Current-Continuous	1.5	Α
Pc	Collector Power Dissipation @ T _C =25℃	60	W
TJ	Junction Temperature 1		$^{\circ}$
T _{stg}	Storage Temperature Range -55~150		$^{\circ}$





	mm		
DIM	MIN	MAX	
Α	19.90	20.10	
В	15.90	16.10	
С	5.50	5.70	
D	0.90	1.10	
F	3.30	3.50	
G	2.90	3.10	
Н	5.90	6.10	
J	0.595	0.605	
K	22.30	22.50	
L	1.90	2.10	
N	10.80	11.00	
0	4.90	5.10	
R	3.75	3.95	
S	3.20	3.40	
U	9.90	10.10	
Y	4.70	4.90	
Z	1.90	2.10	



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ELECTRICAL CHARACTERISTICS

Tc=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP.	MAX	UNIT			
V _{(BR)CEO}	Collector-Emitter Breakdown Voltage	I _C = 10mA; I _B = 0	800			V			
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C = 0.7A; I _B = 0.14A			0.5	V			
V _{BE(sat)}	Base-Emitter Saturation Voltage	I _C = 0.7A; I _B = 0.14A			1.2	V			
I _{CBO}	Collector Cutoff Current	V _{CB} = 800V; I _E = 0			100	μА			
I _{EBO}	Emitter Cutoff Current	V _{EB} = 7V; I _C = 0			100	μА			
h _{FE}	DC Current Gain	I _C = 0.7A; V _{CE} = 4V	10		30				
f _T	Current-Gain—Bandwidth Product	I _E = -0.3A; V _{CE} = 12V		15		MHz			
Сов	Output Capacitance	I _E = 0; V _{CB} = 10V; f _{test} = 1.0MHz		50		pF			
Switching T	ïmes								
ton	Turn-on Time				0.7	μS			
t _{stg}	Storage Time	I _C = 0.7A, I _{B1} = 0.1A; I _{B2} = -0.35A; R _L = 357 Ω; V _{CC} = 250V			4.0	μ \$			
t _f	Fall Time				0.7	μS			

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